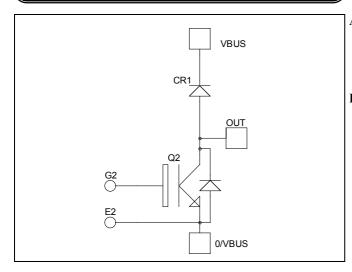
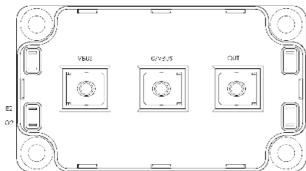


## Boost chopper Fast Trench + Field Stop IGBT3 Power Module







### Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

#### **Features**

- Fast Trench + Field Stop IGBT3 Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

#### Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

#### **Absolute maximum ratings**

Symbol	Parameter		Max ratings	Unit
$V_{CES}$	Collector - Emitter Breakdown Voltage		1200	V
$I_{\mathrm{C}}$	Continuous Collector Current	$T_C = 25^{\circ}C$	280	
	Continuous Conector Current	$T_C = 80$ °C	200	A
$I_{CM}$	Pulsed Collector Current	$T_C = 25$ °C	400	
$V_{GE}$	Gate – Emitter Voltage		±20	V
$P_{D}$	Maximum Power Dissipation	$T_C = 25$ °C	890	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125$ °C	400A @ 1100V	

These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



## All ratings @ $T_j = 25$ °C unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				350	μΑ
V <sub>CE(sat)</sub>	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C	1.4	1.7	2.1	V
		$I_{\rm C} = 200 {\rm A}$ $T_{\rm j} = 125 {\rm ^{\circ}C}$	$T_j = 125$ °C		2.0		·
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$ , $I_C = 3 \text{ mA}$		5.0	5.8	6.5	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				500	nA

**Dynamic Characteristics** 

•	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$ $f = 1MHz$			14		
$C_{oes}$	Output Capacitance				0.8		nF
$C_{res}$	Reverse Transfer Capacitance				0.6		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)			260		
$T_{r}$	Rise Time	$V_{GE} = \pm 15V$			30		ns
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$ $I_C = 200A$			420		
$T_{\mathrm{f}}$	Fall Time	$R_G = 2.7\Omega$		70			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switchin		290		ns	
$T_{\rm r}$	Rise Time	$\begin{aligned} V_{GE} &= \pm 15V \\ V_{Bus} &= 600V \\ I_{C} &= 200A \\ R_{G} &= 2.7\Omega \end{aligned}$			50		
$T_{d(off)}$	Turn-off Delay Time				520		
$T_{\rm f}$	Fall Time				90		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$\Gamma_{\rm j} = 125^{\circ}{\rm C}$		20		m I
E <sub>off</sub>	Turn off Energy	$I_C = 200A$ $R_G = 2.7\Omega$	$\Gamma_{\rm j} = 125^{\circ}{\rm C}$		20		mJ

Chopper diode ratings and characteristics

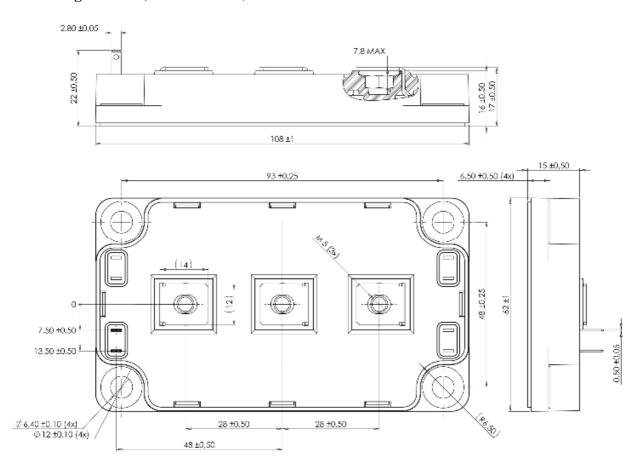
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage			1200			V
$I_{RM}$	Maximum Reverse Leakage Current	V <sub>R</sub> =1200V	$T_i = 25$ °C $T_i = 125$ °C			350 600	μΑ
$I_F$	DC Forward Current		$Tc = 80^{\circ}C$		200		A
V	Diode Forward Voltage	$I_F = 200A$ $V_{GE} = 0V$	$T_i = 25$ °C		1.6	2.1	V
$V_{\mathrm{F}}$			$T_{i} = 125^{\circ}C$		1.6		·
$t_{rr}$	Reverse Recovery Time	1 - 200 4	$T_j = 25^{\circ}C$		170		ns
•rr			$T_j = 125$ °C		280		115
0	Reverse Recovery Charge	$I_F = 200A$ $V_R = 600V$	$T_j = 25$ °C		18		μС
$Q_{rr}$	Reverse Recovery Charge	$di/dt = 2500A/\mu s$	$T_j = 125$ °C		36		μС
$E_{r}$	Reverse Recovery Energy	<u></u>	$T_j = 25$ °C		10		m I
			$T_{i} = 125^{\circ}C$		18		mJ



### Thermal and package characteristics

Symbol	Characteristic			Min	Typ	Max	Unit
$R_{\text{thJC}}$	Junction to Case Thermal Resistance  IGBT  Diode		IGBT			0.14	°C/W
			Diode			0.25	
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
$T_{J}$	Operating junction temperature range Storage Temperature Range			-40		150	°C
$T_{STG}$				-40		125	
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	11.111
Wt	Package Weight					300	g

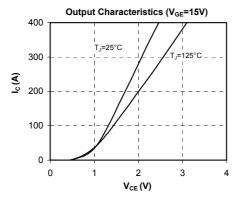
### SP6 Package outline (dimensions in mm)

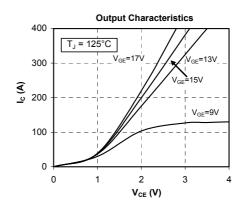


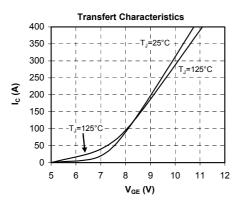
 $See \ application \ note \ APT0601 - Mounting \ Instructions \ for \ SP6 \ Power \ Modules \ on \ www.microsemi.com$ 

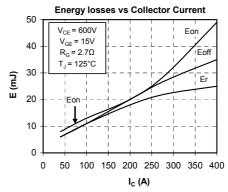


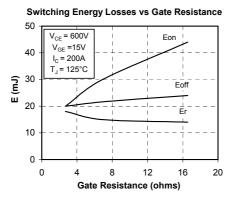
### **Typical Performance Curve**

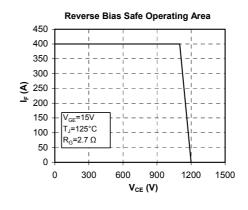


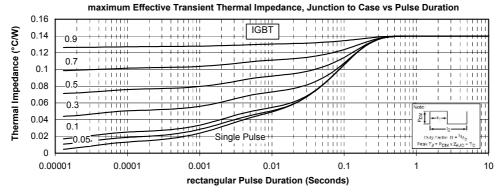




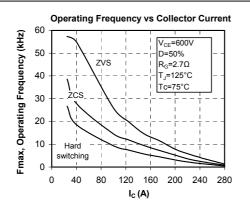


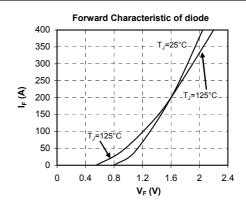


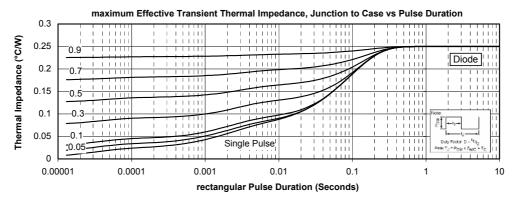














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